

SR302-G Thru. SR308-G

Forward current: 3.0A

Reverse voltage: 20 to 80V

RoHS Device

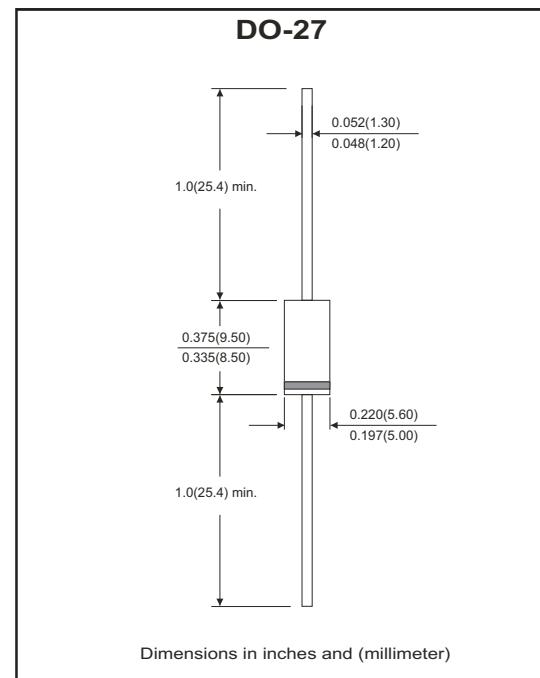


Features

- Fast switching.
- Low forward voltage, high current capability.
- Low power loss, high efficiency.
- High current surge capability.
- High temperature soldering guaranteed: 250°C/10 seconds, 0.375" (9.5mm) lead length at 5lbs (2.3kg) tension.

Mechanical Data

- Case: transfer molded plastic.
- Epoxy: UL94V-0 rate flame retardant.
- Polarity: color band denoted cathode end.
- Lead: plastic axial lead, solderable per MIL-STD-202E, method 208C.
- Mounting position: any.
- Weight: 1.19 grams.



Maximum Ratings and Electrical Characteristics

Ratings at Ta=25°C unless otherwise noted.

Single phase, half wave, 60Hz, resistive or inductive loaded.

For capacitive load, derate current by 20% .

| Parameter | Symbol | SR302-G | SR303-G | SR304-G | SR305-G | SR306-G | SR308-G | Unit | | | | |
|--|------------------|------------|---------|---------|------------|---------|---------|------|--|--|--|--|
| Maximum repetitive peak reverse voltage | V _{RRM} | 20 | 30 | 40 | 50 | 60 | 80 | V | | | | |
| Maximum RMS voltage | V _{RMS} | 14 | 21 | 28 | 35 | 42 | 57 | V | | | | |
| Maximum DC blocking voltage | V _{dc} | 20 | 30 | 40 | 50 | 60 | 80 | V | | | | |
| Maximum average forward rectified current, 0.375" (9.5mm) lead length at TL=75 °C (SR302-G ~ SR304-G) TL=100 °C (SR305-G ~ SR308-G) | I _{AV} | 3.0 | | | | | | A | | | | |
| Peak forward surge current, 8.3ms single half sine-wave, superimposed on rated load (JEDEC method) | I _{FSM} | 150 | | | | | | A | | | | |
| Maximum instantaneous forward voltage at I _f =3A | V _F | 0.55 | | 0.75 | | 0.80 | | V | | | | |
| Maximum DC reverse current at rated DC blocking voltage (Note 1) TA=25 °C TA=100 °C | I _R | 3.0 30 | | | | | | mA | | | | |
| Typical junction capacitance (Note 2) | C _J | 200 | | | | | | pF | | | | |
| Typical thermal resistance (Note 3) | R _{θJA} | 40 | | | | | | °C/W | | | | |
| Operating junction temperature range | T _J | -65 ~ +125 | | | -65 ~ +150 | | | °C | | | | |
| Storage temperature range | T _{STG} | -65 ~ +150 | | | | | | °C | | | | |

Note:

1. Test pulse: 300μS pulse width, 1% duty cycle.

2. Measured at 1MHz and applied reverse voltage of 4.0V.

3. Thermal resistance from junction to ambient P.C.B. mounted with 0.375" (9.5mm) lead length with 2.5"×2.5"(63.5×63.5mm) copper pads.

Schottky Barrier Rectifier

Comchip
SMD Diode Specialist

RATING AND CHARACTERISTIC CURVES (SR302-G Thru. SR308-G)

Fig.1 Typical Forward Current Derating Curve

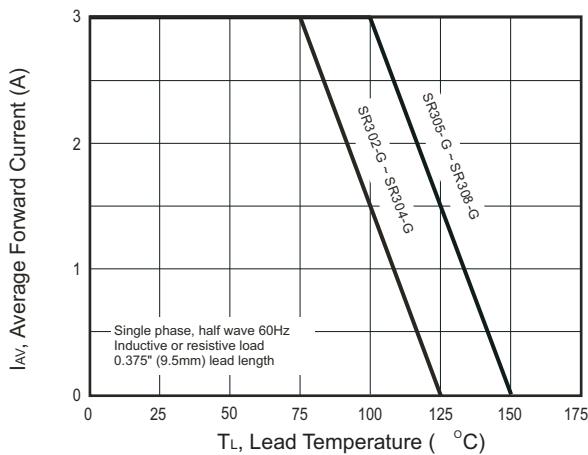


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

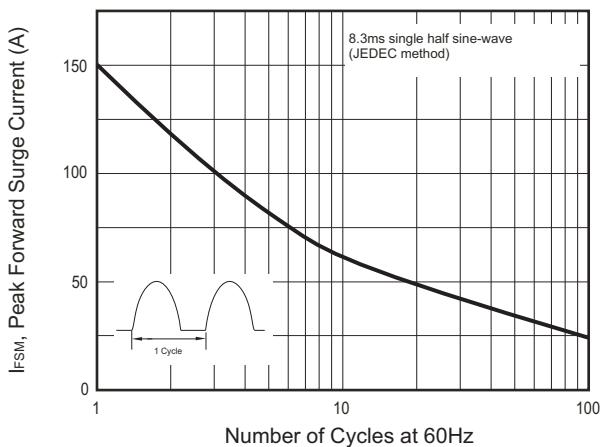


Fig.3 Typical Instantaneous Forward Characteristics

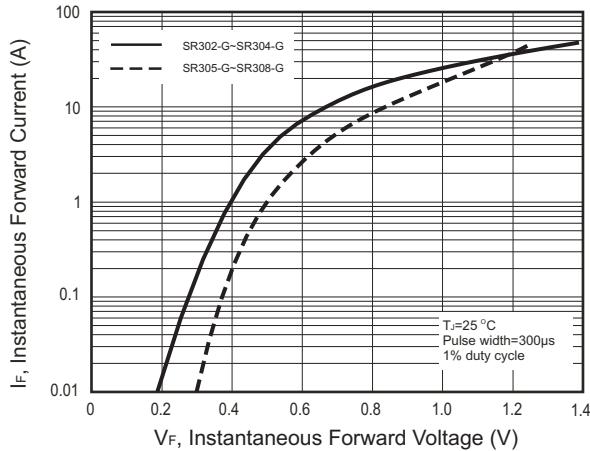


Fig.4 Typical Reverse Characteristics

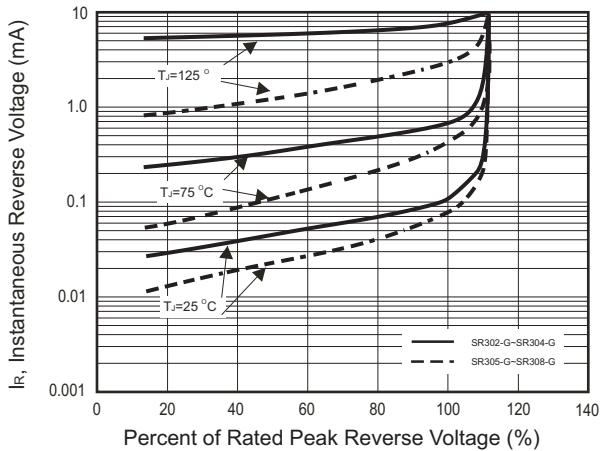


Fig.5 Typical Junction Capacitance

